AMENDMENTS TO THE CLAIMS

Please cancel claims 42-43 and 51-52, and amend claims 24, 26, 47 and 49 according to the following list of claims.

1-20. (Canceled)

21. (Currently Amended) A method for manufacturing semiconductor devices, the method comprising:

providing a semiconductor wafer with a front surface having a plurality of circuit elements formed thereon, wherein the semiconductor wafer has a back surface opposite to the front surface;

forming on the front surface a plurality of electrodes connected to the circuit elements;

inserting the wafer into a burn-in apparatus, wherein the semiconductor wafer is positioned in a positioning plate having a hole, the hole being formed in a shape conforming to an outer shape of the semiconductor wafer;

testing the circuit elements in the burn-in apparatus for electrical functions, through the electrodes, with the back surface of the wafer exposed to convective air in the burn-in apparatus; and

dividing the wafer into a plurality of semiconductor devices.

- 22. (Previously Presented) A method according to claim 21, wherein said dividing includes dividing the wafer after said testing.
- 23. (Previously Presented) A method according to claim 22, further comprising: mounting the wafer on a circuit board with an elastic sheet interposed therebetween, including electrically connecting wiring circuits on the circuit board to the electrodes on the wafer through conductive elastic portions of the elastic sheet.

24. (Currently Amended) A method according to claim 23, further comprising: disposing over the back surface of the wafer a holding plate having a through hole; and pressing the wafer on the circuit board with the holding plate; and

pressing the water on the circuit board with the holding plate; and

providing the convective air over the back surface of the wafer through the through hole.

- 25. (Previously Presented) A method according to claim 22, further comprising: mounting the wafer on a circuit board with a film interposed therebetween, including electrically connecting wiring circuits on the circuit board to the electrodes on the wafer through bump electrodes in the film.
- disposing over the back surface of the wafer a holding plate having a through hole;

 and

 pressing the wafer on the circuit board with the holding plate; and

 providing the convective air over the back surface of the wafer through the through hole.

(Currently Amended) A method according to claim 25, further comprising:

27. (Previously Presented) A method according to claim 21, further comprising the step of forming a plurality of solder balls as the electrodes.

28-43. (Canceled)

26.

44. (Previously Presented) A method for manufacturing semiconductor devices, the method comprising:

preparing a semiconductor wafer with a first surface and a second surface, the second surface being opposite to the first surface, wherein the first surface has a plurality of circuit elements formed thereon;

forming a plurality of electrodes on the first surface, the electrodes being connected to the circuit elements;

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inserting the semiconductor wafer into a burn-in apparatus, wherein the semiconductor wafer is positioned in a positioning plate having a hole, the hole being formed in a shape conforming to an outer shape of the semiconductor wafer;

testing the circuit elements in the burn-in apparatus for electrical function, through the electrodes, with the second surface of the semiconductor wafer exposed to convective air in the burn-in apparatus; and

dividing the semiconductor wafer into the plurality of semiconductor devices.

- 45 (Previously Presented) A method according to claim 44, wherein the dividing includes dividing the semiconductor wafer after the testing.
- 46. (Previously Presented) A method according to claim 45, further comprising mounting the semiconductor wafer on a circuit board with an elastic sheet interposed therebetween, including electrically connecting wiring circuits on the circuit board to the electrodes on the semiconductor wafer through conductive elastic portions of the elastic sheet.
- 47. (Currently Amended) A method according to claim 46, further comprising: disposing over the second surface of the semiconductor wafer a holding plate having a through hole; and

pressing the semiconductor wafer on the circuit board with the holding plate; and providing the convective air over the second surface of the semiconductor wafer through the through hole.

- 48. (Previously Presented) A method according to claim 45, further comprising mounting the semiconductor wafer on a circuit board with a film interposed therebetween, including electrically connecting wiring circuits on the circuit board to the electrodes on the semiconductor wafer through bump electrodes in the film.
 - 49. (Currently Amended) A method according to claim 48, further comprising:

disposing over the second surface of the semiconductor wafer a holding plate having a through hole; and

pressing the semiconductor wafer on the circuit board with the holding plate; and providing the convective air over the second surface of the semiconductor wafer through the through hole.

50. (Previously Presented) A method according to claim 44, further comprising forming a plurality of solder balls as the electrodes.

51-52. (Canceled)

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